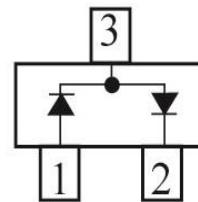
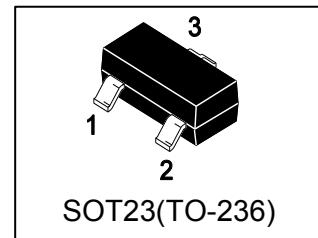




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- Fast Switching Speed
- For General Purpose Switching Applications
- High Conductance

| BAV99 |
|------------|
| |
| MARKING:A7 |
| |



Solid dot = Green molding compound device,
if none, the normal device

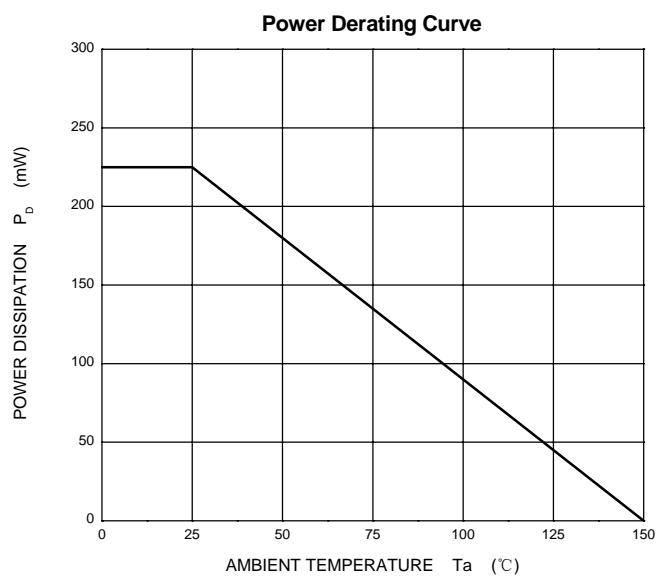
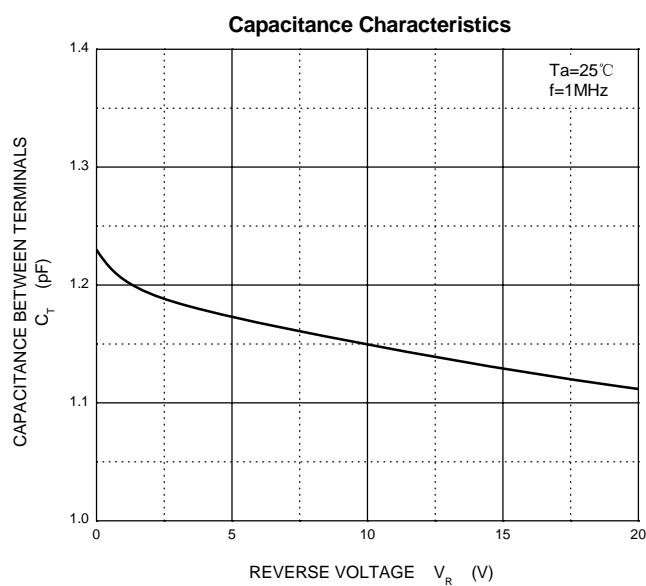
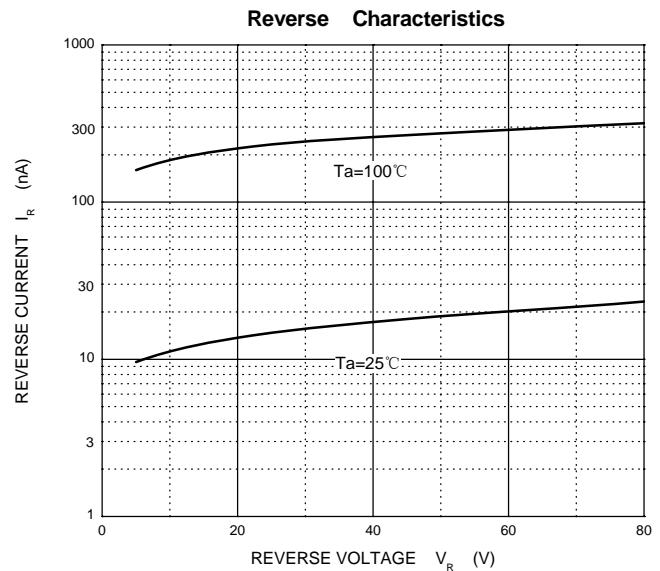
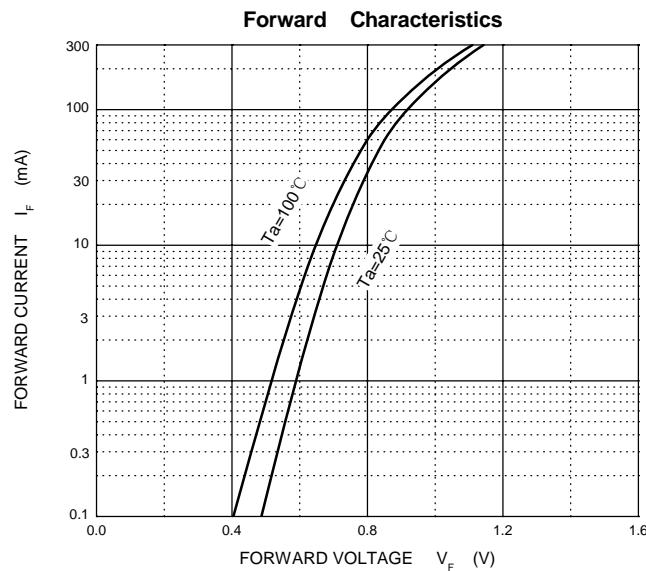
Maximum Ratings @Ta=25°C

| Parameter | Symbol | Limit | Unit |
|--|------------------|----------|------|
| Reverse Voltage | V _R | 70 | V |
| Forward Current | I _F | 200 | mA |
| Non-Repetitive Peak Forward Surge Current @t=8.3ms | I _{FSM} | 2.0 | A |
| Power Dissipation | P _D | 225 | mW |
| Thermal Resistance Junction to Ambient | R _{θJA} | 556 | °C/W |
| Junction Temperature | T _J | 150 | °C |
| Storage Temperature range | T _{STG} | -55~+150 | °C |

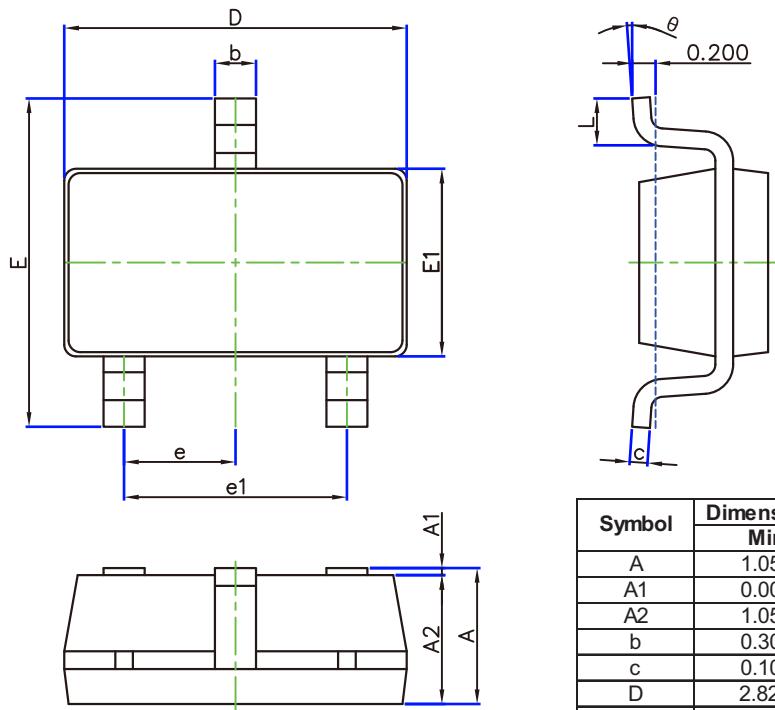
Electrical Characteristics @Ta=25°C

| Parameter | Symbol | Min | Typ | Max | Unit | Conditions |
|-------------------------------|-----------------|-----|-----|-------|------|---|
| Reverse breakdown voltage | V _R | 70 | | | V | I _R =100μA |
| Forward voltage | V _{F1} | | | 0.715 | V | I _F =1mA |
| | V _{F2} | | | 0.855 | V | I _F =10mA |
| | V _{F3} | | | 1 | V | I _F =50mA |
| | V _{F4} | | | 1.25 | V | I _F =150mA |
| Reverse current | I _R | | | 2.5 | μA | V _R =70V |
| Capacitance between terminals | C _T | | | 1.5 | pF | V _R =0,f=1MHz |
| Reverse recovery time | t _{rr} | | | 6 | ns | I _F = I _R = 10mA, I _{rr} = 0.1 × I _R , R _L = 100Ω |

Typical Characteristics

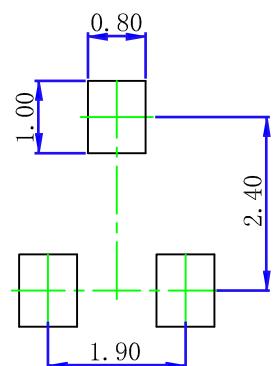


SOT-23 Package Outline Dimensions



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 1.050 | 1.250 | 0.041 | 0.049 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 1.050 | 1.150 | 0.041 | 0.045 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.100 | 0.200 | 0.004 | 0.008 |
| D | 2.820 | 3.020 | 0.111 | 0.119 |
| E1 | 1.500 | 1.700 | 0.059 | 0.067 |
| E | 2.650 | 2.950 | 0.104 | 0.116 |
| e | 0.950(BSC) | | 0.037(BSC) | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.300 | 0.600 | 0.012 | 0.024 |
| θ | 0° | 8° | 0° | 8° |

SOT-23-3L Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

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